

END-LOOK PACKAGE BRIGHT EMITTING DIODE

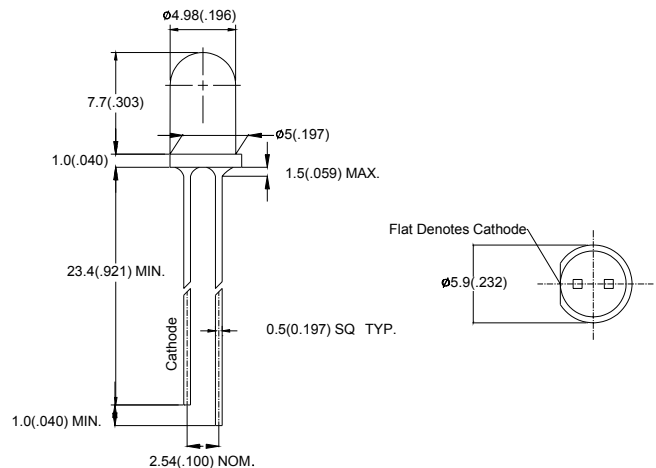
● Features:

1. High radiant power and high radiant intensity.
2. Standard T-1 1/4(5mm)package.
3. Peak wavelength $\lambda_p=940\text{nm}$.
4. Good spectral matching to si-photodetector.
5. Radiant angle: 60°
6. Lens Appearance: Water Clear
7. This product doesn't contain restriction substance, comply ROHS standard

● Applications:

1. Remote Control.
2. Automatic Control System.

● Package Dimensions:



NOTES:

1. All dimensions are in millimeters (inches).
2. Tolerance is $\pm 0.25\text{mm}$ (0.01") unless otherwise specified.
3. Lead spacing is measured where the leads emerge from the package.
4. Specifications are subject to change without notice.

● Absolute Maximum Ratings($T_a=25^\circ\text{C}$)

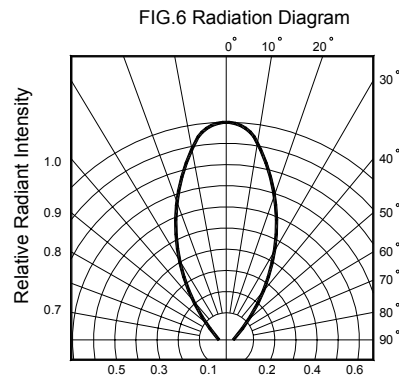
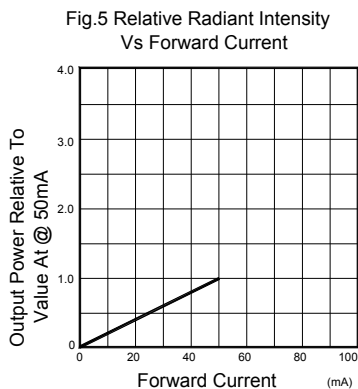
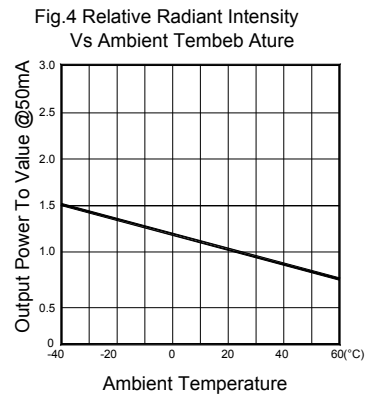
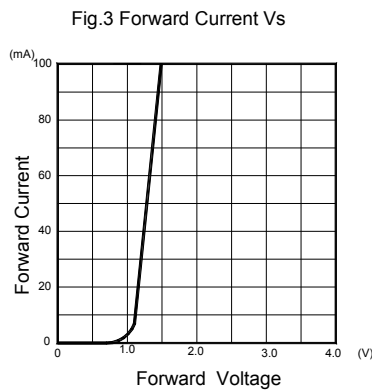
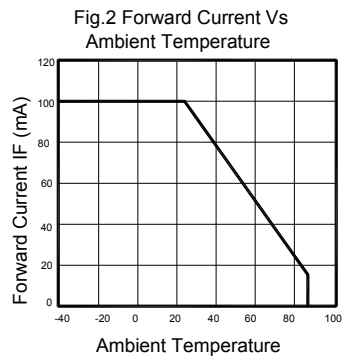
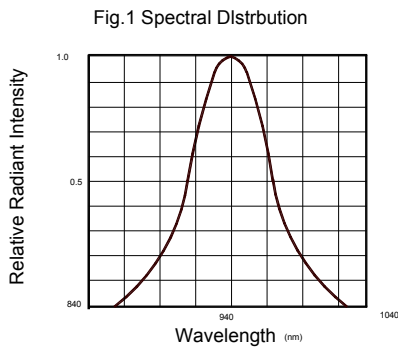
Parameter	Symbol	Rating	Unit
Power Dissipation	P_d	100	mW
Continuous Forward Current	I_F	100	mA
Peak Forward Current ^{*1}	I_{FP}	1.0	A
Reverse Voltage	V_R	5	V
Operating Temperature	T_{opr}	$-45^\circ\text{C} \sim 85^\circ\text{C}$	-
Storage Temperature	T_{stg}	$-45^\circ\text{C} \sim 100^\circ\text{C}$	-
Soldering Temperature	T_{sol}	260°C (for 5 seconds)	-

*1 Condition for is I_{FP} pulse of 1/10 duty and 0.1 msec width.

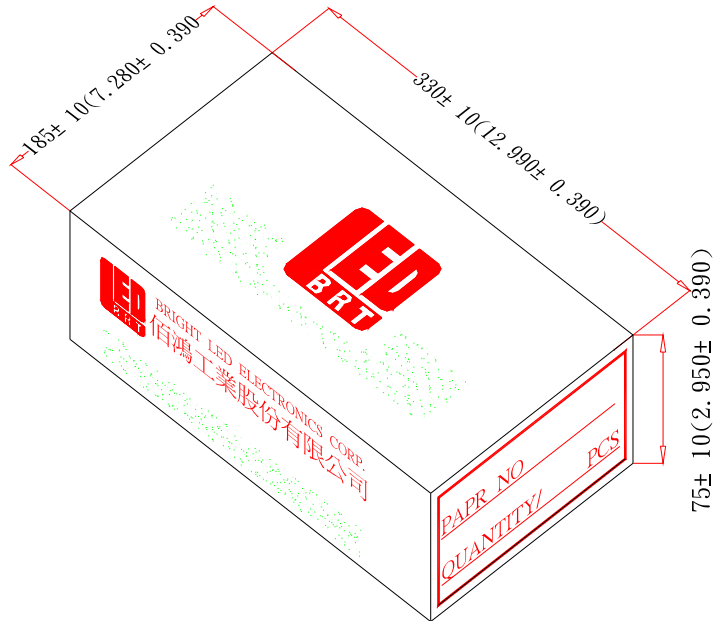
● **Optical- Electrical Characteristics (@ $T_A=25^{\circ}C$)**

Parameter	Symbol	Test Conditions	Min	TYP	Max	Unit
Radiant Intensity	I_e	$I_f=50mA$	8.41	17.06	-	mW/sr
Forward Voltage	V_F	$I_f=50mA$	-	1.25	1.5	V
Reverse Current	I_R	$V_R=5V$	-	-	100	μA
Peak Wavelength	λ_p	$I_f=20mA$	-	940	-	nm
Spectral Line Half- Width	$\Delta \lambda$	$I_f=20mA$	-	50	-	nm
Viewing Angle	$2\theta_{1/2}$	$I_f=20mA$	-	60	-	deg

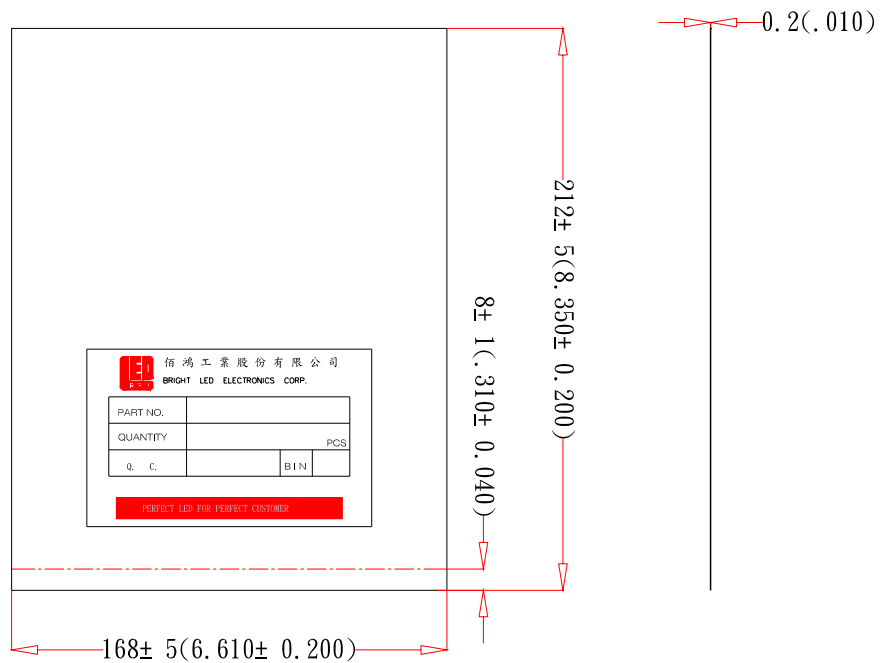
● **Typical Optical-Electrical Characteristic Curves**



● Tapping and packaging specifications(Units: mm)



● Packaging Bag Dim



Notes:

- 1、500pcs per bag, 5Kpcs per box.
- 2、All dimensions are in millimeters(inches).
- 3、Specifications are subject to change without notice.



Infrared Emitting Diode Specification

- Commodity: Infrared emitting diode
- Intensity Bin Limits (At 50mA)

BIN CODE	Min.(mW/sr)	Max.(mW/sr)
10	6.00	11.38
11	8.41	15.95
12	11.78	22.33
13	16.50	31.28
14	23.12	43.79
15	32.36	61.30